

Socay TVS Diodes 400w 22V Surface Mount Transient Voltage Suppressors SMAJ22A SMC

Basic Information

- Place of Origin:
- Brand Name:
- Certification:
- Model Number:
- Minimum Order Quantity: 5000PCS
- Price: Negotiable
- Delivery Time:

Shenzhen, Guangdong, China SOCAY

UL,REACH,RoHS,ISO SMAJ22A

5-8 work days

DO-214AC



Product Specification

- Package Type:
- Reverse Stand-Off Voltage 22V Vrwm:
- Breakdown Voltage Vbr@lt 24.4V (Min.):
- Breakdown Voltage Vbr@lt 26.9V (Max.):
- Test Current It: 1mA
- 35.5V • Vc@lpp:
- 11.27A • Ipp:
- Maximum Reverse Leakage5µA Ir@Vrwm:

Socay TVS Diodes 400w 22V Surface Mount Transient Voltage Suppressors SMAJ22A SMC

DATASHEET: <u>SMAJ_v2207.1.pdf</u>

Brief introduction:

The SMAJ series is designed for the protection of electronic equipment from voltage transients due to lightning and other transient voltage events.

Application:

TVS devices are perfect for safeguarding I/O interfaces, VCC bus, and other vulnerable circuits utilized in Telecom, Computer, Industrial, and Consumer electronic applications.

Part Number		Merking		Revers e Stand-		kdown ge VBR V) ❷IT	Test Curre	Maximu m Clampi ng	um	Maximu m Reverse Leakag
Uni	Bi	Uni	Bi	Voltage VRWM(V)		МАХ	IT(mA)	Voltage VC @IPP (V)	Curren t IPP (A)	e IR @VRW Μ (μΑ)
SMAJ45 A	SMAJ45 CA	сv	YV	45.0	50.00	55.30	1	72.7	5.50	5
A	SMAJ48 CA	сх	YX	48.0	53.30	58.90	1	77.4	5.17	5
SMAJ51 A	SMAJ51 CA	cz	ΥZ	51.0	56.70	62.70	1	82.4	4.85	5
SMAJ54 A	CA	RE	ZE	54.0	60.00	66.30	1	87.1	4.59	5
SMAJ58 A	SMAJ58 CA	RG	ZG	58.0	64.40	71.20	1	93.6	4.27	5
SMAJ60 A	CA	RK	zκ	60.0	66.70	73.70	1	96.8	4.13	5
SMAJ64 A	SMAJ64 CA	RM	zм	64.0	71.10	78.60	1	103.0	3.88	5
SMAJ70 A	SMAJ70 CA	RP	ZP	70.0	77.80	86.00	1	113.0	3.54	5
SMAJ75 A	SMAJ75 CA	RR	ZR	75.0	83.30	92.10	1	121.0	3.31	5
SMAJ78 A	SMAJ78 CA	RT	ZT	78.0	86.70	95.80	1	126.0	3.17	5
SMAJ80 A	SMAJ80 CA	RB	ZB	80.0	88.80	97.60	1	129.6	3.09	5
SMAJ85 A	SMAJ85 CA	RV	zv	85.0	94.40	104.00	1	137.0	2.92	5
SMAJ90 A	CA	RX	zx	90.0	100.00	111.00	1	146.0	2.74	5
SMAJ100 A	SMAJ100 CA	RZ	zz	100.0	111.00	123.00	1	162.0	2.47	5
SMAJ110 A	SMAJ110 CA	SE	VE	110.0	122.00	135.00	1	177.0	2.26	5
Δ	(:A	30	VG	120.0	133.00	147.00	1	193.0	2.07	5
A	SMAJ130 CA		vк	130.0	144.00	159.00	1	209.0	1.91	5
A	SMAJ140 CA		νв	140.0	155.00	171.00	1	226.8	1.76	5
A	SMAJ150 CA		∨м	150.0	167.00	185.00	1	243.0	1.65	5
SMAJ160 A	SMAJ160 CA	SP	VP	160.0	178.00	197.00	1	259.0	1.54	5
Δ	(:A	SN	VR	170.0	189.00	209.00	1	275.0	1.45	5
A	SMAJ180 CA		VТ	180.0	201.00	220.00	1	291.6	1.37	5
A	SMAJ190 CA		vv	190.0	211.00	232.00	1	307.8	1.30	5
SMAJ200 A	SMAJ200 CA	sw	vw	200.0	224.00	247.00	1	324.0	1.23	5
SMAJ220 A	SMAJ220 CA	sx	vx	220.0	246.00	272.00	1	356.0	1.12	5
SMAJ250 A	SMAJ250 CA	sz	vz	250.0	279.00	309.00	1	405.0	0.99	5

SMAJ300 A	ICA		HE	300.0	335.00	371.00	1	486.0	0.82	5
SMAJ350 A	(,A		HG	350.0	391.00	432.00	1	567.0	0.71	5
SMAJ400 A	LA		нк	400.0	447.00	494.00	1	648.0	0.62	5
SMAJ440 A	SMAJ440 CA	DM	НМ	440.0	492.00	543.00	1	713.0	0.56	5

Notes:

.1.Suffix 'A ' denotes 5% tolerance device.

2.Add suffix ' CA ' after part number to specify Bi-directional devices.

3. For Bi-Directional devices having V_R of 10 volts and under, the I $_R$ limit is double.

Characteristics:

The junction is passivated with glass Low inductance Low leakage Uni and Bidirectional unit The clamping capability is excellent Plated with matte tin that is lead-free. Halogen free and RoHS compliant To optimize board space for surface mounted applications The plastic package has a flammability rating of Underwriters Laboratory 94V-0. Over-specification of voltage or current is a common cause of failure The Whisker test is conducted according to JEDEC JESD201A, specifically following its table 4a and 4c. The device has a peak power capability of 400W when using a 10 × 1000µs waveform repetition rate (duty cycle) of 0.01%. Fast response time: typically less than 1.0ps from 0 Volts to VBR min Typical infrared (IR) is less than 5 microamps (µA) above 12 volts. Soldering at high temperatures: terminals should be heated to 260°C for 40 seconds. IEC-61000-4-2 ESD 15kV(Air), 8kV (Contact) Typical maximum temperature coefficient $\Delta VBR = 0.1\% \times VBR@25^{\circ}C \times \Delta T$ ESD protection of data lines in accordance with IEC 61000-4-2(IEC801-2) EFT protection of data lines in accordance with IEC 61000-4-4(IEC801-4)





Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation with a 10/1000µs waveform (Fig.1)(Note 1), (Note 2)	P _{PPM}	400	Watts
Peak Pulse Current with a 10/1000µs waveform.(Note1,Fig.3)	I _{PP}	See Next Table	Amps
Power Dissipation on Infinite Heat Sink at T _L =75°C	P _{M(AV)}	1.0	Watt
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	I _{FSM}	40	Amps

Maximum Instantaneous Forward Voltage at 25A for Unidirectional Only (Note 4)	·r		Voltage
Operating junction and Storage Temperature Range.	T _J , T _{STG}	-55 to +150	

Notes:

 Apply a non-repetitive current pulse as shown in Figure 3 and derate above TA = 25 as per Figure 2. 2.
Mount the device on 5.0mm x 5.0mm (0.03mm thick) copper pads on each terminal.
The device should produce a single half sine-wave or equivalent square wave with a duration of 8.3ms. The duty cycle should not exceed 4 pulses per minute. Non-essential fillers have been removed. 4.The forward voltage (VF) should be less than 3.5V for VBR values below 200V and less than 6.5V for VBR values above

201V. All units and metrics should be strictly adhered to.

	Socay [®] Shenzhen Socay Electronics Co., Ltd.							
	C	+8618126201429	0	sylvia@socay.com	e	socaydiode.com		
4/F	, Block C, HeH			ogy Park, 19 MinQing F Dong Province, China	Road, L	ongHua District, Shenzhen City,		